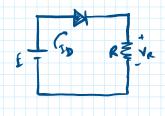
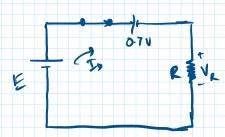
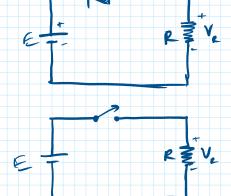
SERIES DIODE CONFIGURATION WITH A RESISTOR

Forward bios



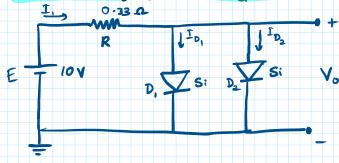


Reverse bias





PARALLEL DIODE CONFIGURATION WITH A RESISTOR



Voltage drop across all diodes in parallel is the same; current is divided

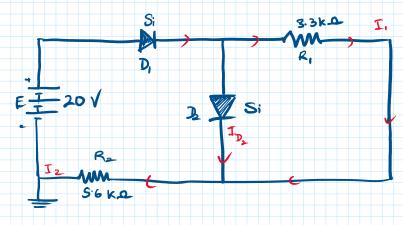
$$I_1 = V_2 = 10 - 0.7 = 9.3 = 28.18 \times 10^{-3} A$$

$$R = 0.33 \times 10^3 = 0.33 \times 10^3$$

$$I_1 = V_2 = 10 - 0.7 = 9.3 = 28.18 \times 10^{-3} A$$
 $I_{D_1} = I_{D_2} = I_1 = 28.18 \times 10^{-3} A$

identical diades

SERIES - PARALLEL DIODE CONFIGURATION



Hint: Note that both diodes are forward biased.

$$20 - 0.7 - 0.7 - 5.6(I_{2}) = 0$$

$$-5.6I_{1} = -20 + 0.7 + 0.7$$

$$I_{2} = 3.821 \times 10^{-3} A$$

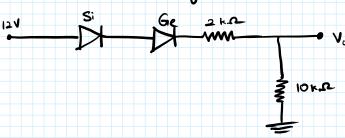
$$I_{1} = \frac{V_{2}}{R_{1}} = \frac{0.7}{3.3 \times 10^{3}} = 0.212 \times 10^{-3} A$$

$$I_2 = I_1 + I_{p_2}$$

 $3.321 \times 10^3 = 0.212 \times 10^{-3} + I_{p_2}$
 $I_{p_2} = 3.109 \times 10^{-3} A$

PROBLEMS

g: Determine the level of Vo



$$\frac{30 \ln 12 - 0.7 - 0.3 - 2 \times 10^{3} (I) - 10 \times 10^{3} (I) = 0}{-12 \times 10^{3} (I) = -11}$$

$$I = 0.916 \times 10^{-3}$$

$$T = \frac{39.3}{6.8 \times 10^3} = 5.78 \text{ mA}$$

$$V_0 = 20 - 6.8 (5.78 \times 10^{-3})$$

= 20 - (39.304 × 10⁻³) = 20

$$= 20 - \left(39.304 \times 10^{-3}\right) = 20 - 0.0393 = 19.961 \text{ V}$$

9. Delenmine Vo, and Voe for the networks

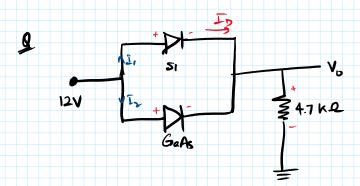
S:

4.7ks

Vo,

Vo,

GaAs



$$V_0 = 12 - 0.7 = 11.3 \text{V}$$

$$12 - 0.7 - 4.7(I) = 0$$

$$I = \frac{11.3}{4.7 \times 10^{2}} = 2.404 \times 10^{-3} \text{ A}$$

